

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE020N30K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =180A

 $R_{DS(ON)}$ =1.9 m Ω @ V_{GS} =10V (Typ)

 $R_{DS(ON)}$ =2.6 m Ω @ V_{GS} =4.5V (Typ)

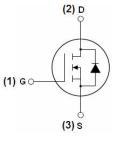
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE020N30K	NCE020N30K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	180	А
Drain Current-Continuous(Tc=100°ℂ)	I _D (100℃)	127	Α
Pulsed Drain Current	I _{DM}	720	Α
Maximum Power Dissipation	P _D	135	W
Single pulse avalanche energy (Note 5)	E _{AS}	1300	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	R _{0JC}	1.11	°C/W
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NCE020N30K

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	1.0	1.6	2.5	V
Dunin Course On Chata Basistanas	Ь	V _{GS} =10V, I _D =20A	-	1.9	2.3	0
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A		2.6	3.4	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =20A	-	35	-	S
Dynamic Characteristics (Note4)						,
Input Capacitance	C _{lss}	\\ 45\\\\ 0\\	-	7264	-	PF
Output Capacitance	Coss	V_{DS} =15V, V_{GS} =0V, F=1.0MHz	-	1049	-	PF
Reverse Transfer Capacitance	Crss	F=1.UIVIHZ	-	949	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	20	-	nS
Turn-on Rise Time	t _r	V _{DD} =15V,I _D =40A	-	50	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =6 Ω	-	120	-	nS
Turn-Off Fall Time	t _f		-	50	-	nS
Total Gate Charge	Qg)/ 45\/\ 00A	-	156.1		nC
Gate-Source Charge	Q _{gs}	V _{DS} =15V,I _D =20A,	-	15.7		nC
Gate-Drain Charge	Q _{gd}	- V _{GS} =10V	-	40.9		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	180	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 40A	-	56	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	125	-	nC
Forward Turn-On Time	ton	Intrinsic turn-on time is negl	igible (turi	n-on is do	ominated b	y LS+LD)

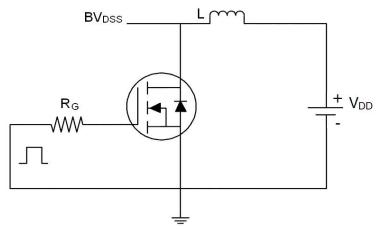
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** E_{AS} condition : Tj=25 $^{\circ}$ C,V_{DD}=40V,V_G=10V,L=0.5mH,Rg=25 Ω .

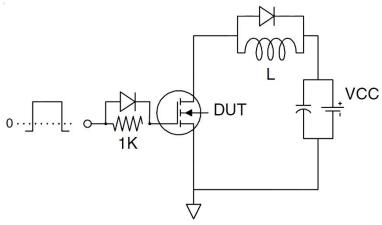


Test circuit

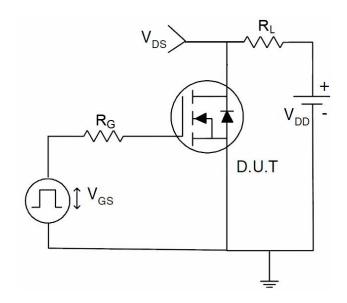
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



3



Typical Electrical and Thermal Characteristics (Curves)

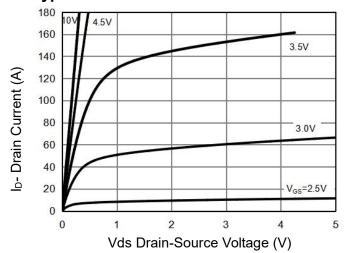


Figure 1 Output Characteristics

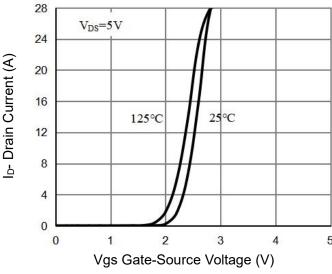


Figure 2 Transfer Characteristics

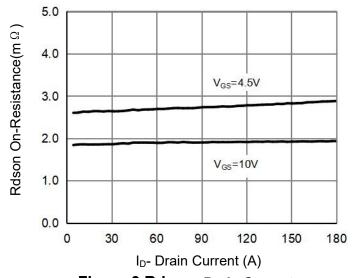


Figure 3 Rdson- Drain Current

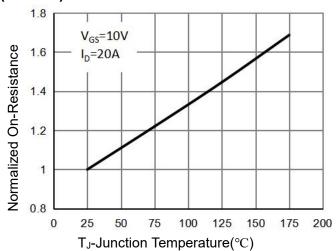


Figure 4 Rdson-JunctionTemperature

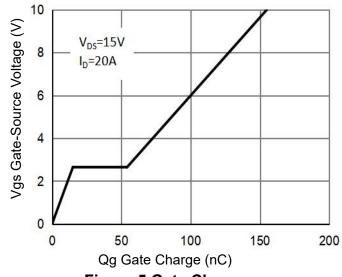


Figure 5 Gate Charge

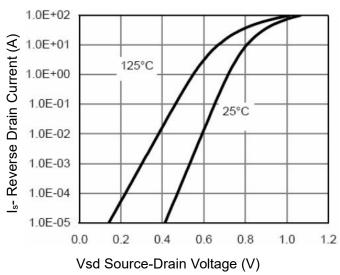


Figure 6 Source- Drain Diode Forward



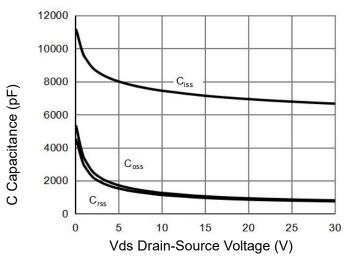


Figure 7 Capacitance vs Vds

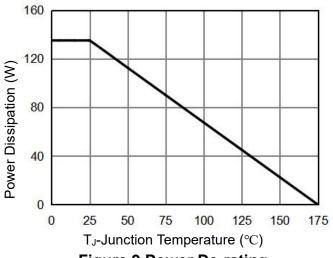


Figure 9 Power De-rating

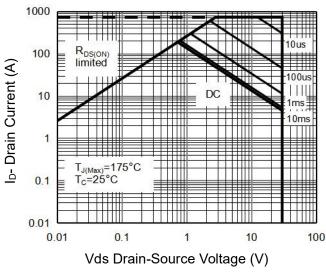


Figure 8 Safe Operation Area

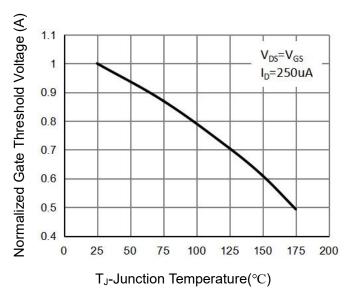


Figure 10 V_{GS(th)} vs Junction Temperature

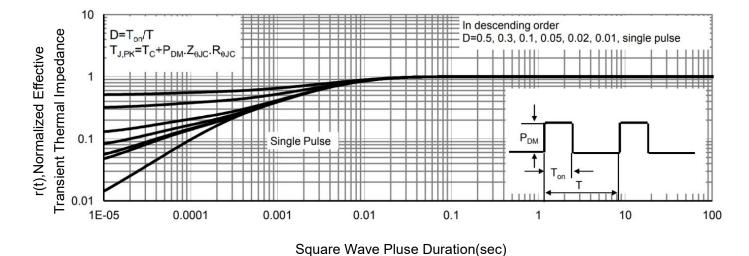
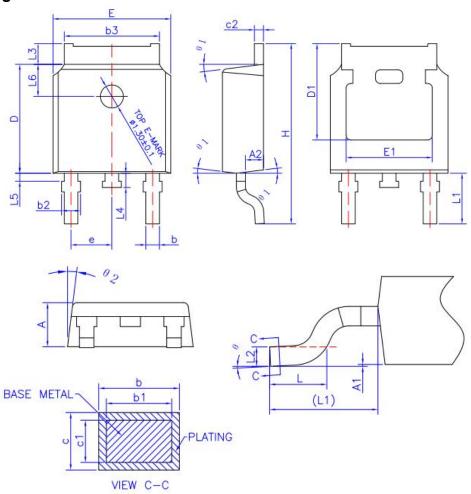


Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



COMMON DIMENSIONS (UNITS OF MEASURE =MILLIMETER)

SYMBOL	MIN	NOM	MAX		
A	2.20	2.30	2.38		
A1	0		0.10		
A2	0.90	1.01	1.10		
b	0.72		0.85		
b1	0.71	0.76	0.81 0.90 5.46 0.60		
b2	0.72	0 -1-1			
b3	5.13	5.33			
С	0.47				
c1	0.46	0.51	0.56		
c2	0.47	-	0.60		
D	6.00	6.10	6.20		
D1	5.25	0-2-2			
E	6.50	6.60	6.70		
E1	4.70				
e	2.186	2.286	2.386		
Н	9.80	10.10	10.40		
L	1.40	1.50	1.70		
L1	2	.90 REF			
L2	0.508 BSC				
L3	0.90	0.90			
L4	0.60	0.80	1.00		
L5	0.15				
L6	1.80 REF				
θ	0°		8°		
01	5°	7°	9°		
θ2	5°	7°	90		

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